MACOM

100 Chelmsford Street Lowell, MA 01851 +1 978.656.2500

www.macom.com



2nd June 2022

PCN-01549

Digi-Key Corporation 701 Brooks Ave South Thief River Falls, Minnesota 56701

Subject: Additional testing and packaging site.

Dear Valued Customer,

MACOM Technology Solutions has a goal of providing redundant manufacturing capability for increased surge capacity as well as an uninterrupted supply chain. In alignment with this goal, we are pleased to announce an additional testing and packaging site for the parts listed in the next pages.

In addition to our current testing and packaging sites, we planned to test and package these parts at our long-standing Contract Manufacturer, Year 2000, Ho Chi Minh City, Vietnam. Year 2000 is a valued, high-quality manufacturing partner for many MACOM products.

In accordance with MACOM Technology Solutions' customer notification policy, you are receiving this notice because you have purchased one or more of the products listed in the previous two-year period.

Please contact your local sales representative if you have any specific questions.

Sincerely

Tom Galluccio
Director, Product Marketing
thomas.galluccio@macom.com



Appendix I Affected part numbers

Part Number	Part type
M5X5536	Diode
MLP7130-11	Diode
MX51267-11	Diode
MX51316-11	Diode
MX51333-11	Diode
M3X1175	Capacitor
M3X3027	Capacitor

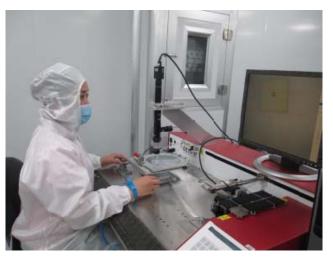


Appendix IIThe new testing and assembly facility











Appendix III Qualification process capability data

Two representative part numbers (MX51267-11 and MC2S022025-025) are tested and qualified in Year 2000 as below, and the rest parts in the pcn can be qualified by similarity to the representative parts as they have the same production process.

1. Diode.

MX51267-11

Test conditions: IR1max=10uA, under -1100V.

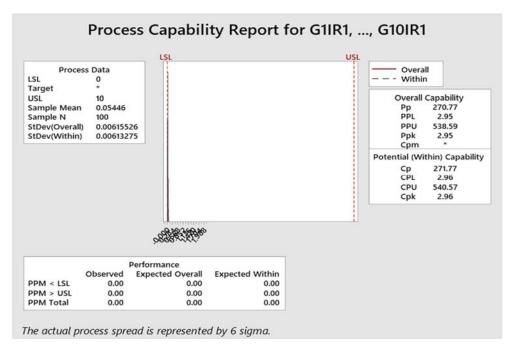
IR2max=0.05uA, under -1000V.

Cj1max=0.25pF, under -28V.

VF1max=1.25V, under 100mA.

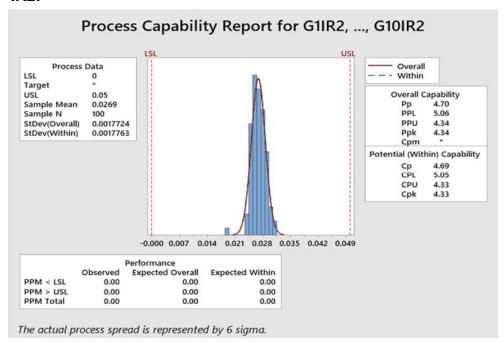
Sample size=100,10 sub-groups.

IR1:

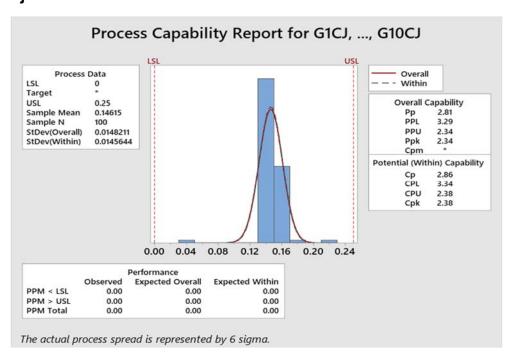




IR2:

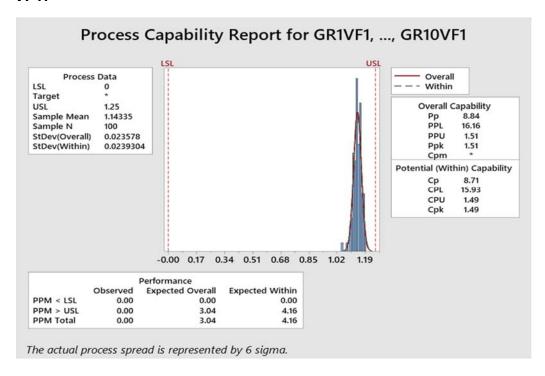


Cj1:





VF1:





2. Capacitor.

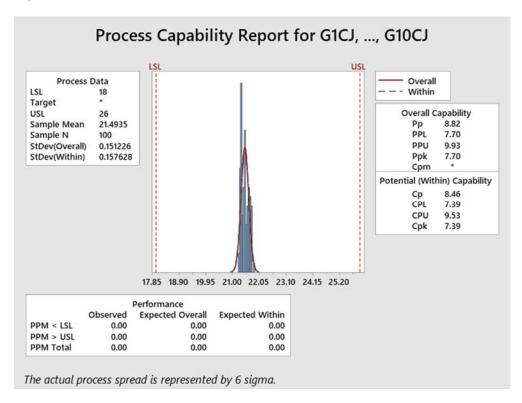
MC2S022025-025

Test conditions: Cj1min=18pF, Cj1max=26pF, under 0V.

VBmin=50V, under -10uA.

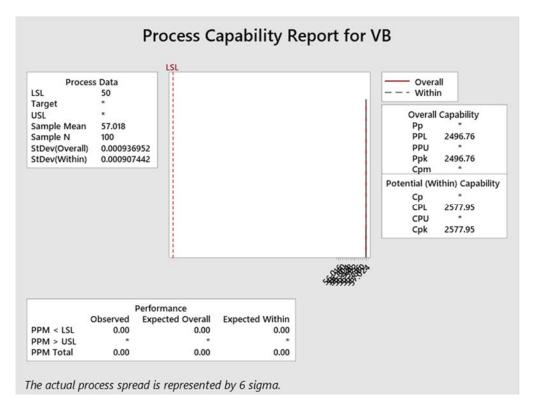
Sample size=100,10 sub-groups.

CJ1:





VB:



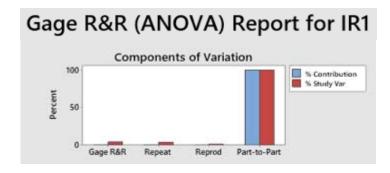


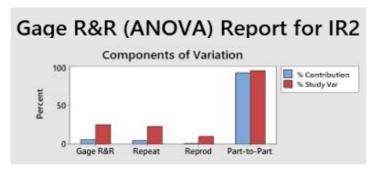
Appendix IV Qualification Gage R&R testing data

1. Diode test parameters

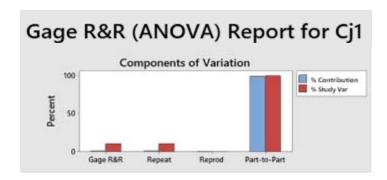
GR&R summary:

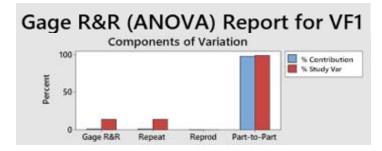
Specification:-			
a) GR&R Contribution % ≦10%			
b) GR&R Variat	tion % ≦30%		
	GR&R	GR&R	Danulé
Parameter	Contribution 0/	Mariatian0/	Result
Parameter	Contribution %	Variation%	
Parameter	GR&R	GR&R	
IR1			PASS
	GR&R	GR&R	PASS PASS
IR1	GR&R 0.21	GR&R 4.57	
IR1 IR2	GR&R 0.21 6.62	GR&R 4.57 25.72	PASS











2. Capacitor test parameters

GR&R summary:

Specification:-			
a) GR&R Contr	ribution % ≦10%		
b) GR&R Varia	tion % ≦30%		
Parameter	GR&R Contribution % GR&R	GR&R Variation% GR&R	Result
VB	5.69	23.85	PASS

